Product data sheet

1. General description

Ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- High thermal cycling performance
- Low thermal resistance
- Low forward volt drop
- · Soft recovery minimizes power-consuming oscillations

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- Output rectifiers in high-frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		400			V	
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 123$ °C; Fig. 1; Fig. 2	9		А		
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 123 °C; square-wave pulse	18		А		
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;		100 A			
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	110			Α	
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics		'				
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>		-	0.9	1.03	V
		I _F = 8 A; T _j = 25 °C; <u>Fig. 4</u>		-	1.05	1.25	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 4</u>		-	1.2	1.4	V
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; Fig. 5; Fig. 7		-	50	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	
2	Α	anode		K — A 001aaa020
mb	mb	mounting base; cathode	1 2 TO-220AC (SOD59)	001aaa020

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BYV29-400	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59		

7. Marking

Table 4. Marking codes

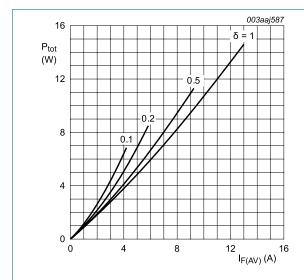
Type number	Marking codes
BYV29-400	BYV29-400

8. Limiting values

Table 5. Limiting values

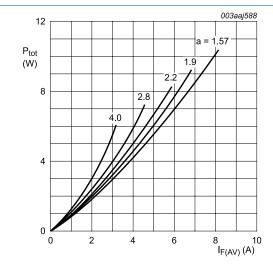
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		400	V
V_{RWM}	crest working reverse voltage		400	V
V_R	reverse voltage	DC	400	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 123$ °C; Fig. 1; Fig. 2	9	А
I _{FRM}	repetitive peak forward current	$δ = 0.5$; $t_p = 25 \mu s$; $T_{mb} \le 123 °C$; square-wave pulse	18	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	100	Α
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	110	А
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 0.890 \text{ V}; R_s = 0.019 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.890 V; R_s = 0.019 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig 3	-	-	2.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

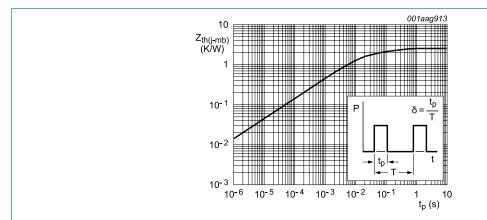
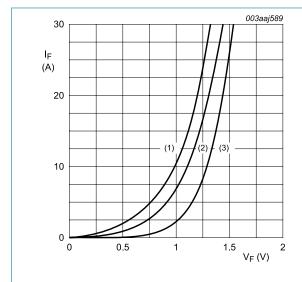


Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V_{F}	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.05	1.25	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.9	1.03	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.2	1.4	V
I _R	reverse current	V _R = 400 V; T _j = 25 °C	-	2	50	μA
		V _R = 400 V; T _j = 100 °C	-	0.1	0.35	mA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A/s};$ $T_j = 25 \text{ °C}; Fig. 5; Fig. 6$	-	40	60	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/s};$ $T_j = 25 \text{ °C}; Fig. 5; Fig. 7$	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/s};$ $T_j = 100 \text{ °C}; Fig. 5; Fig. 8$	-	4	5.5	А
V_{FRM}	forward recovery voltage	$I_F = 10 \text{ A}; \text{ d}I_F/\text{dt} = 10 \text{ A/s};$ $T_j = 25 \text{ °C}; \text{ Fig. 9}$	-	2.5	-	V



(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) $T_i = 25$ °C; maximum values

 $V_o = 0.890 \text{ V}; R_s = 0.019 \Omega$

Fig. 4. Forward current as a function of forward voltage

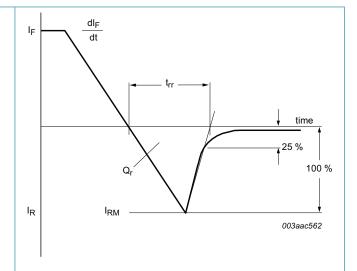
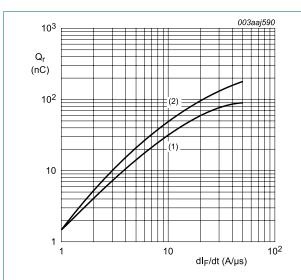
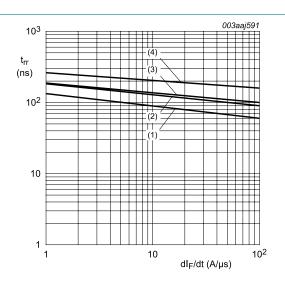


Fig. 5. Reverse recovery definitions; ramp recovery



(1)
$$I_F = 2 A$$
; $T_j = 25 °C$
(2) $I_F = 10 A$; $T_j = 25 °C$

Fig. 6. Recovered charge as a function of rate of change of forward current; maximum values

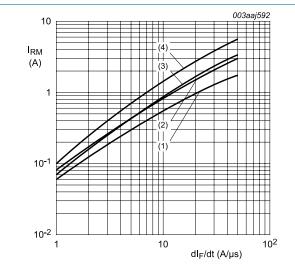


(1)
$$I_F = 1 \text{ A}$$
; $T_j = 25 \text{ °C}$
(2) $I_F = 1 \text{ A}$; $T_i = 100 \text{ °C}$

(3)
$$I_F = 10 \text{ A}$$
; $T_j = 25 ^{\circ}\text{C}$

 $(4) I_F = 10 A; T_i = 100 °C$





(1) $I_F = 1 A$; $T_j = 25 °C$ (2) $I_F = 1 A$; $T_j = 100 °C$

(3) $I_F = 10 \text{ A}$; $T_j = 25 \text{ °C}$ (4) $I_F = 10 \text{ A}$; $T_j = 100 \text{ °C}$

Fig. 8. Peak reverse recovery current as a function of rate of change of forward current; maximum values

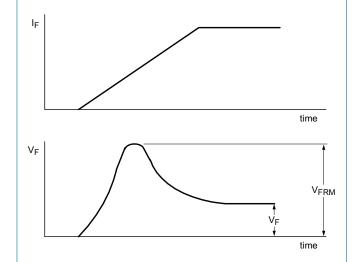
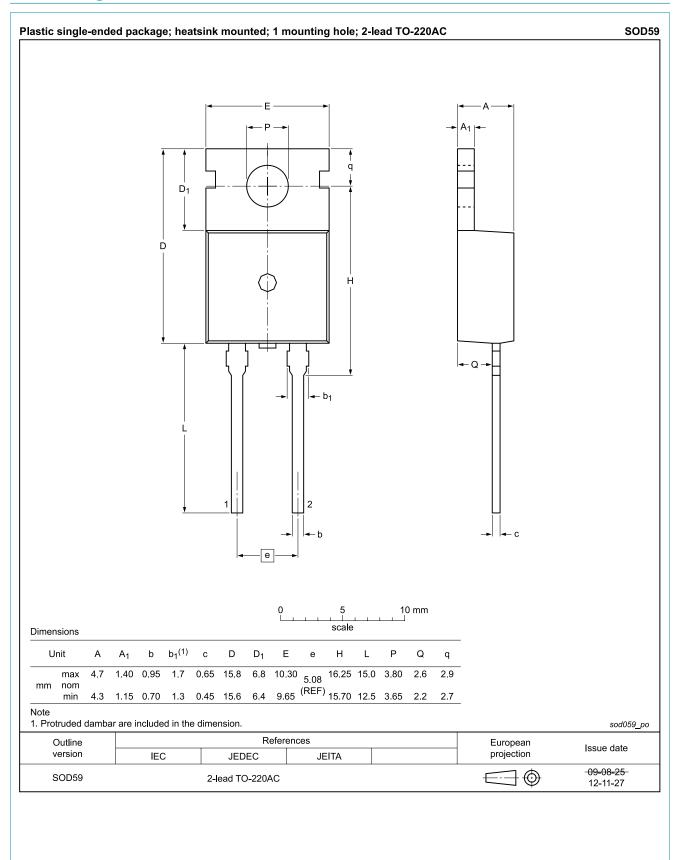


Fig. 9. Forward recovery definitions

11. Package outline



12. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BYV29-400 v.4	20180305	Product data sheet	-	BYV29-400 v.3			
Modifications: Change from NXP version to WeEn version							
BYV29-400 v.3	20120529	Product data sheet	-	BYV29_SERIES v.2			
Modifications: • Type number BYV29-400 separated from data sheet BYV29_SERIES v.2. • Various changes to content.							
BYV29_SERIES v.2	19980901	Product specification	-	BYV29_SERIES v.1			

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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